

74AUP2G06

Low power dual inverter with open-drain output

Rev. 02 — 25 March 2010

Product data sheet

1. General description

The 74AUP2G06 provides two inverting buffers with open-drain output. The output of the device is an open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114F Class 3A. Exceeds 5000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101D exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu\text{A}$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

3. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74AUP2G06GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP2G06GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP2G06GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891

4. Marking

Table 2. Marking

Type number	Marking code ^[1]
74AUP2G06GW	p6
74AUP2G06GM	p6
74AUP2G06GF	p6

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

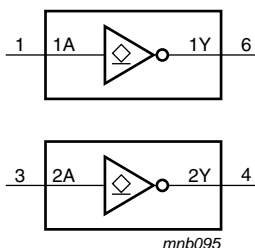


Fig 1. Logic symbol

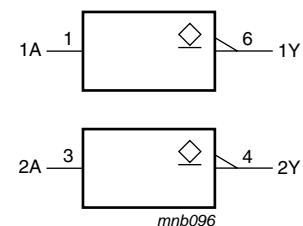


Fig 2. IEC logic symbol

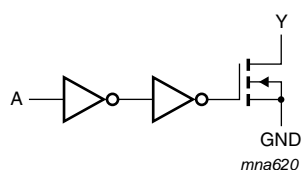
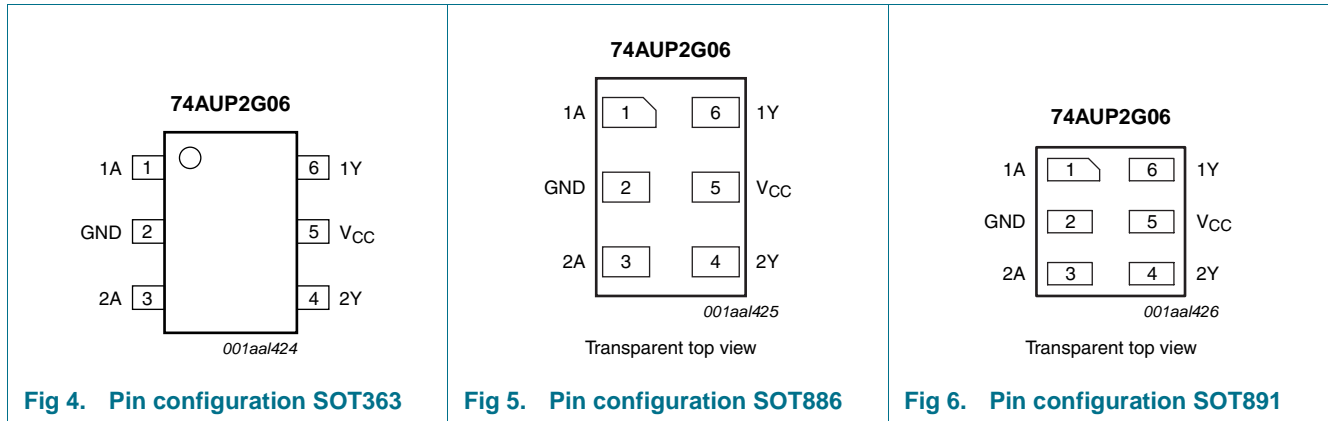


Fig 3. Logic diagram (one driver)

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
1A, 2A	1, 3	data input
GND	2	ground (0 V)
1Y, 2Y	6, 4	data output
V _{CC}	5	supply voltage

7. Functional description

7.1 Function table

Table 4. Function table^[1]

Input nA	Output nY
L	Z
H	L

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
V_I	input voltage		[1] -0.5	+4.6	V
I_{OK}	output clamping current	$V_O < 0$ V	-50	-	mA
V_O	output voltage	Active mode and Power-down mode	[1] -0.5	+4.6	V
I_O	output current	$V_O = 0$ V to V_{CC}	-	+20	mA
I_{CC}	supply current		-	+50	mA
I_{GND}	ground current		-50	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[2] -	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 package: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.
For XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		0.8	3.6	V
V_I	input voltage		0	3.6	V
V_O	output voltage	Active mode	0	V_{CC}	V
		Power-down mode; $V_{CC} = 0$ V	0	3.6	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 0.8$ V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25$ °C						
V_{IH}	HIGH-level input voltage	$V_{CC} = 0.8$ V	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9$ V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC} = 2.3$ V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0$ V to 3.6 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 0.8$ V	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9$ V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3$ V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0$ V to 3.6 V	-	-	0.9	V

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V		
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	V _I = V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	40	μA
C _I	input capacitance	V _{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.8	-	pF
C _O	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
		output disabled; V _O = GND; V _{CC} = 0 V	-	1.1	-	pF
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V		
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{OZ}	OFF-state output current	$V_I = V_{IL}$; $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$	-	-	± 0.5	μA
I_{OFF}	power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V}$	-	-	± 0.5	μA
ΔI_{OFF}	additional power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }0.2\text{ V}$	-	-	± 0.6	μA
I_{CC}	supply current	$V_I = \text{GND}$ or V_{CC} ; $I_O = 0\text{ A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	-	-	0.9	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6\text{ V}$; $I_O = 0\text{ A}$; $V_{CC} = 3.3\text{ V}$	-	-	50	μA
$T_{amb} = -40\text{ }^\circ\text{C to }+125\text{ }^\circ\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 0.8\text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9\text{ V to }1.95\text{ V}$	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	1.6	-	-	V
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 0.8\text{ V}$	-	-	$0.25 \times V_{CC}$	V
		$V_{CC} = 0.9\text{ V to }1.95\text{ V}$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	-	0.7	V
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	-	-	0.9	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20\text{ }\mu\text{A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	-	-	0.11	V
		$I_O = 1.1\text{ mA}$; $V_{CC} = 1.1\text{ V}$	-	-	$0.33 \times V_{CC}$	V
		$I_O = 1.7\text{ mA}$; $V_{CC} = 1.4\text{ V}$	-	-	0.41	V
		$I_O = 1.9\text{ mA}$; $V_{CC} = 1.65\text{ V}$	-	-	0.39	V
		$I_O = 2.3\text{ mA}$; $V_{CC} = 2.3\text{ V}$	-	-	0.36	V
		$I_O = 3.1\text{ mA}$; $V_{CC} = 2.3\text{ V}$	-	-	0.50	V
		$I_O = 2.7\text{ mA}$; $V_{CC} = 3.0\text{ V}$	-	-	0.36	V
	$I_O = 4.0\text{ mA}$; $V_{CC} = 3.0\text{ V}$	-	-	0.50	V	
I_I	input leakage current	$V_I = \text{GND to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$	-	-	± 0.75	μA
I_{OZ}	OFF-state output current	$V_I = V_{IL}$; $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$	-	-	± 0.75	μA
I_{OFF}	power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V}$	-	-	± 0.75	μA
ΔI_{OFF}	additional power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }0.2\text{ V}$	-	-	± 0.75	μA
I_{CC}	supply current	$V_I = \text{GND}$ or V_{CC} ; $I_O = 0\text{ A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	-	-	1.4	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6\text{ V}$; $I_O = 0\text{ A}$; $V_{CC} = 3.3\text{ V}$	-	-	75	μA

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit	
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)		
C_L = 5 pF										
t _{pd}	propagation delay	nA to nY; see Figure 7								
		V _{CC} = 0.8 V	-	12.8	-	-	-	-	ns	
		V _{CC} = 1.1 V to 1.3 V	2.3	4.3	9.9	2.0	10.9	12.0	ns	
		V _{CC} = 1.4 V to 1.6 V	1.8	3.1	6.1	1.5	7.1	7.8	ns	
		V _{CC} = 1.65 V to 1.95 V	1.5	2.8	4.7	1.2	5.7	6.3	ns	
		V _{CC} = 2.3 V to 2.7 V	1.2	2.2	3.2	1.0	3.9	4.3	ns	
		V _{CC} = 3.0 V to 3.6 V	1.1	2.2	3.3	0.8	3.6	4.0	ns	
C_L = 10 pF										
t _{pd}	propagation delay	nA to nY; see Figure 7								
		V _{CC} = 0.8 V	-	15.8	-	-	-	-	ns	
		V _{CC} = 1.1 V to 1.3 V	2.7	5.4	11.2	2.5	13.2	15.0	ns	
		V _{CC} = 1.4 V to 1.6 V	2.2	3.9	7.0	2.0	8.5	9.4	ns	
		V _{CC} = 1.65 V to 1.95 V	1.9	3.6	5.4	1.7	6.7	7.4	ns	
		V _{CC} = 2.3 V to 2.7 V	1.7	2.9	3.8	1.4	4.5	5.0	ns	
		V _{CC} = 3.0 V to 3.6 V	1.6	3.2	4.6	1.2	4.9	5.4	ns	
C_L = 15 pF										
t _{pd}	propagation delay	nA to nY; see Figure 7								
		V _{CC} = 0.8 V	-	18.8	-	-	-	-	ns	
		V _{CC} = 1.1 V to 1.3 V	3.2	6.4	12.2	2.9	15.2	17.0	ns	
		V _{CC} = 1.4 V to 1.6 V	2.6	4.6	7.7	2.3	9.4	10.0	ns	
		V _{CC} = 1.65 V to 1.95 V	2.3	4.5	6.6	2.1	7.3	8.1	ns	
		V _{CC} = 2.3 V to 2.7 V	2.1	3.5	4.6	1.7	5.1	5.7	ns	
		V _{CC} = 3.0 V to 3.6 V	2.0	4.0	6.0	1.5	6.5	7.2	ns	
C_L = 30 pF										
t _{pd}	propagation delay	nA to nY; see Figure 7								
		V _{CC} = 0.8 V	-	27.8	-	-	-	-	ns	
		V _{CC} = 1.1 V to 1.3 V	4.4	9.3	16.5	3.9	19.3	21.3	ns	
		V _{CC} = 1.4 V to 1.6 V	3.6	6.8	10.1	3.2	12.0	13.2	ns	
		V _{CC} = 1.65 V to 1.95 V	3.2	6.8	10.7	2.9	11.0	12.1	ns	
		V _{CC} = 2.3 V to 2.7 V	2.9	5.3	7.2	2.6	7.8	8.6	ns	
		V _{CC} = 3.0 V to 3.6 V	2.9	6.5	10.5	2.5	10.8	11.9	ns	

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C_L = 5 pF, 10 pF, 15 pF and 30 pF									
C _{PD}	power dissipation capacitance	f _i = 1 MHz; V _I = GND to V _{CC} ^[3]							
		V _{CC} = 0.8 V	-	0.5	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	0.6	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	0.7	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	0.7	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	1.0	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	1.2	-	-	-	-	pF

- [1] All typical values are measured at nominal V_{CC}.
- [2] t_{pd} is the same as t_{PZL} and t_{PLZ}.
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N$ where:
 f_i = input frequency in MHz;
 V_{CC} = supply voltage in V;
 N = number of inputs switching.

12. Waveforms

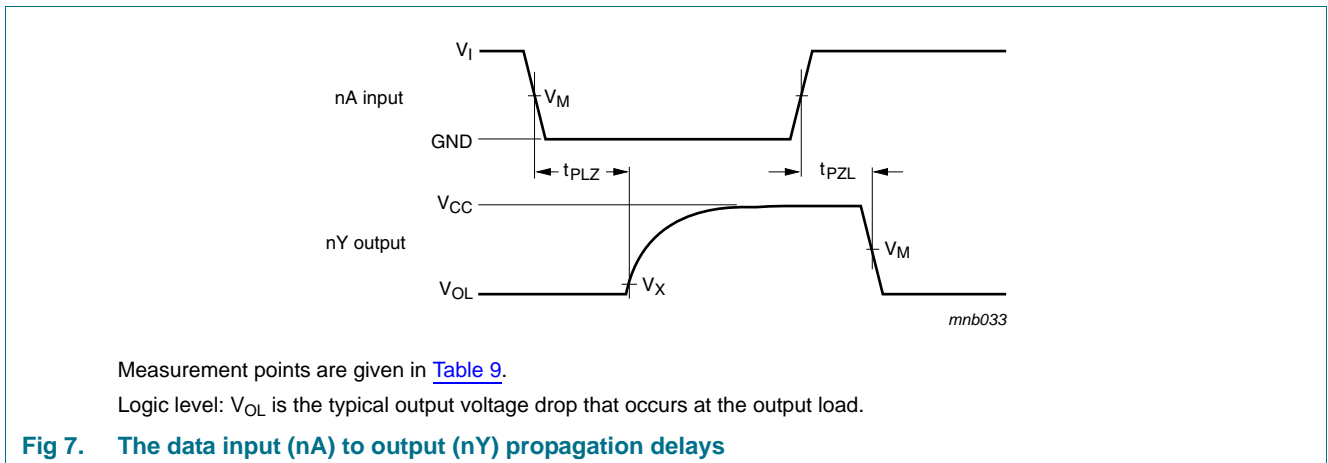
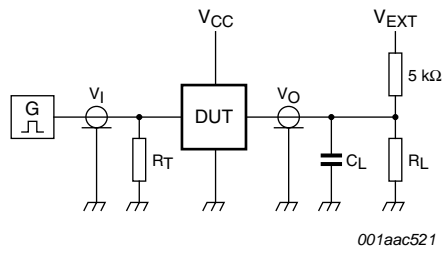


Table 9. Measurement points

Supply voltage	Input	Output	
V _{CC}	V _M	V _M	V _X
0.8 V to 1.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.1 V
1.65 V to 2.7 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.15 V
3.0 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.3 V



Test data is given in [Table 10](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 8. Load circuitry for switching times

Table 10. Test data

Supply voltage	Load		V_{EXT}		
V_{CC}	C_L	R_L [1]	t_{PLH} , t_{PHL}	t_{PZH} , t_{PHZ}	t_{PZL} , t_{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 \text{ M}\Omega$.

13. Package outline

Plastic surface-mounted package; 6 leads

SOT363

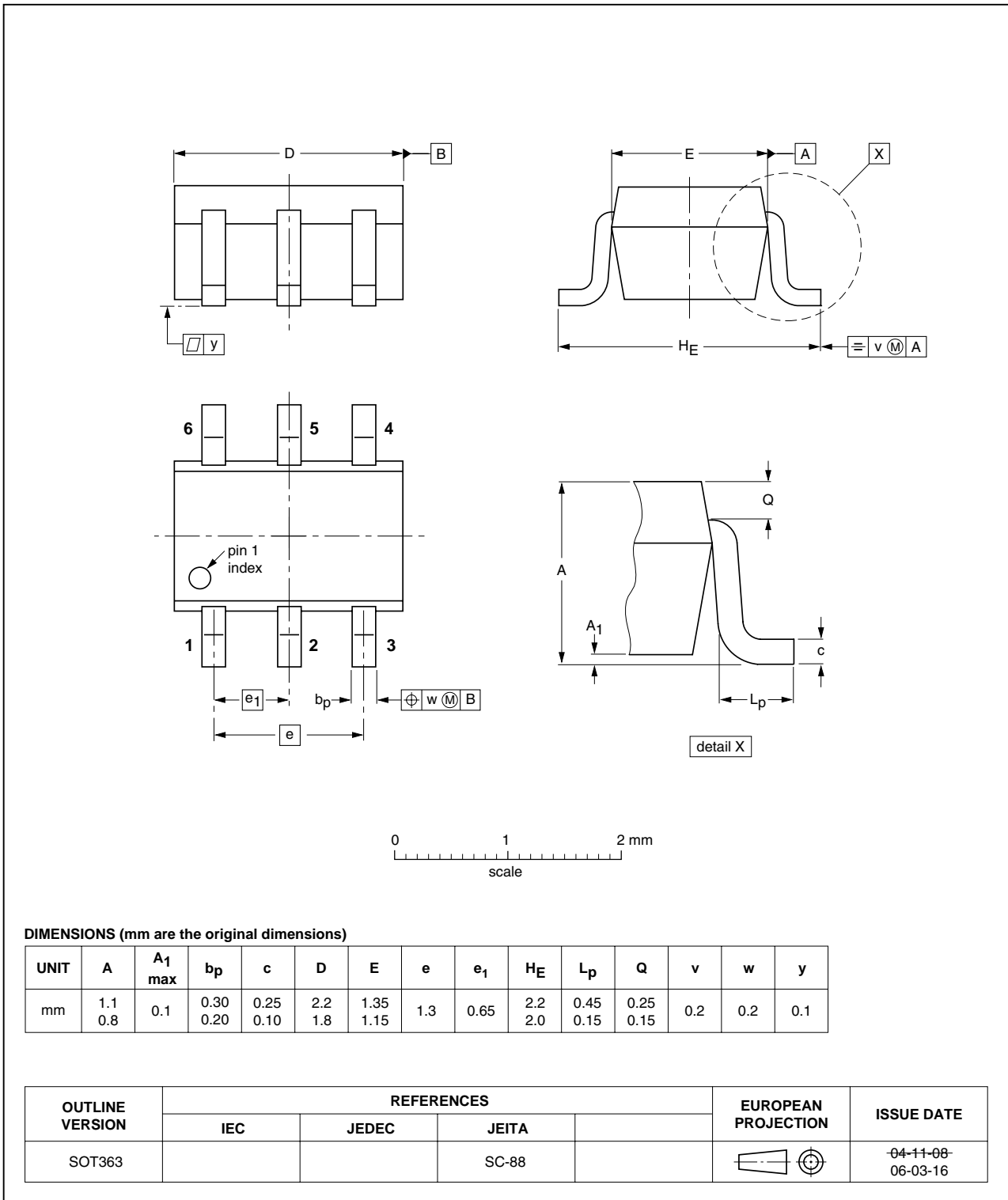


Fig 9. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

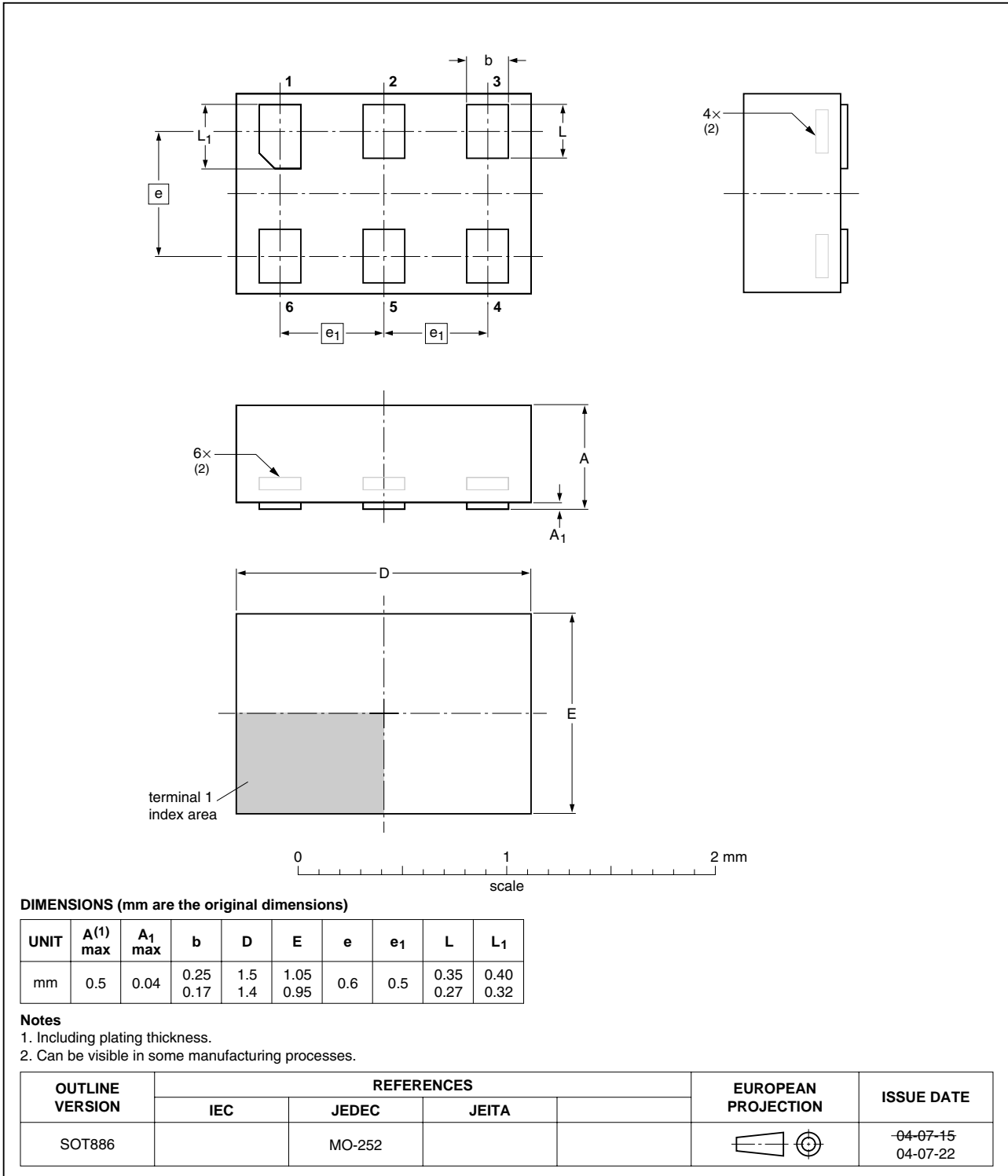


Fig 10. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

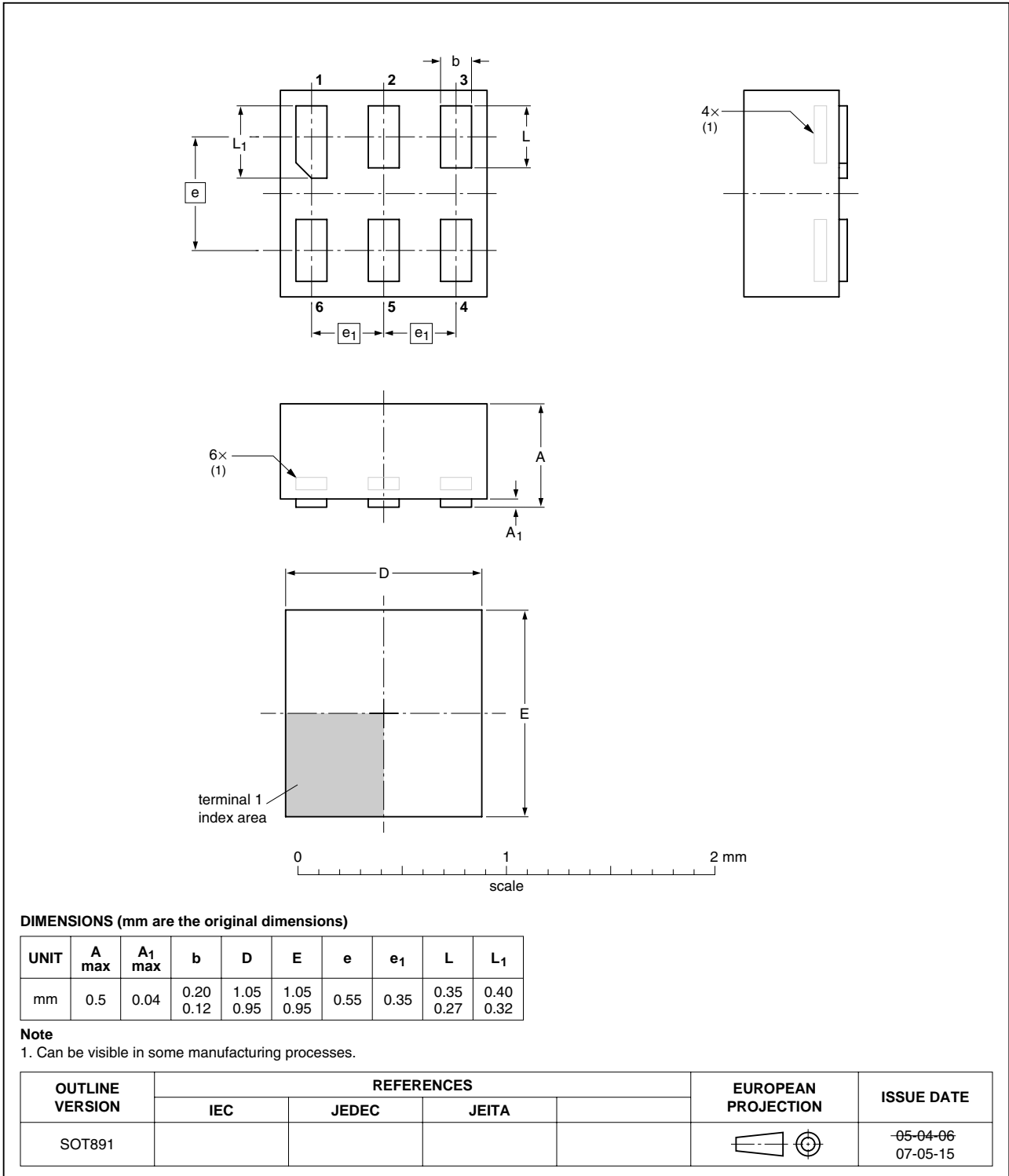


Fig 11. Package outline SOT891 (XSON6)

14. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

15. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G06_2	20100325	Product data sheet	-	74AUP2G06_1
74AUP2G06_1	20100211	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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